TOSHIBA Field Effect Transistor Silicon N Channel MOS Type ( $\pi$ -MOSVII)

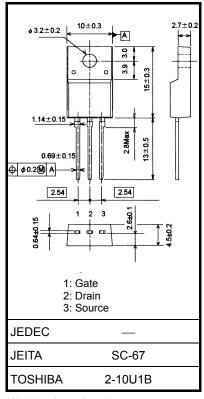
# TK7A50D

#### Switching Regulator Applications

- Low drain-source ON-resistance: R<sub>DS</sub> (ON) = 1.0 Ω (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 2.5 \text{ S}$  (typ.)
- Low leakage current:  $I_{DSS}$  = 10  $\mu$ A (max) (V<sub>DS</sub> = 500 V)
- Enhancement mode: V<sub>th</sub> = 2.4 to 4.4 V (V<sub>DS</sub> = 10 V, I<sub>D</sub> = 1 mA)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V <sub>DSS</sub>	500	V	
Gate-source voltage		V <sub>GSS</sub>	±30	V	
Drain current	DC (Note 1)	Ι <sub>D</sub>	7		
	Pulse (t = 1 ms) (Note 1)	I <sub>DP</sub>	28	A	
Drain power dissipation (Tc = 25°C)		PD	35	W	
Single pulse avalanche energy (Note 2)		E <sub>AS</sub>	129	mJ	
Avalanche current		I <sub>AR</sub>	7	А	
Repetitive avalanche energy (Note 3)		E <sub>AR</sub>	3.5	mJ	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

#### Absolute Maximum Ratings (Ta = 25°C)



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	3.57	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	62.5	°C/W

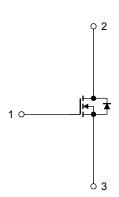
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD}$  = 90 V,  $T_{ch}$  = 25°C (initial), L = 4.5 mH,  $R_G$  = 25  $\Omega$ ,  $I_{AR}$  = 7 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.

#### Internal Connection



Unit: mm

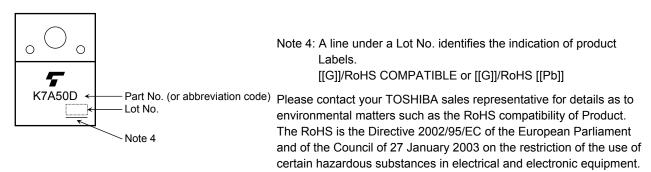
**Electrical Characteristics (Ta = 25°C)** 

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS}=\pm 30~V,~V_{DS}=0~V$			±1	μA
Drain cut-off current		I <sub>DSS</sub>	$V_{DS} = 500 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			10	μA
Drain-source bre	akdown voltage	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	500			V
Gate threshold v	oltage	V <sub>th</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.4		4.4	V
Drain-source ON	l-resistance	R <sub>DS (ON)</sub>	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3.5 \text{ A}$		1.0	1.22	Ω
Forward transfer	admittance	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 3.5 \text{ A}$	0.7	2.5		S
Input capacitance		C <sub>iss</sub>			600		pF
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 25 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}$		4		
Output capacitance		C <sub>oss</sub>	1		70		
Switching time	Rise time	tr	$V_{GS}$ 0 V 0 V V 0 V V 0 V V 0 V V V V V V V V V V V V V V V V V V V		18		ns
	Turn-on time	t <sub>on</sub>			40		
	Fall time	t <sub>f</sub>			8		
	Turn-off time	t <sub>off</sub>	Duty $\leq$ 1%, t <sub>W</sub> = 10 µs	_	55		
Total gate charge		Qg			12		
Gate-source charge		Q <sub>gs</sub>	$V_{DD}\approx 400~V,~V_{GS}=10~V,~I_{D}=7~A$		7		nC
Gate-drain charge		Q <sub>gd</sub>	]		5		

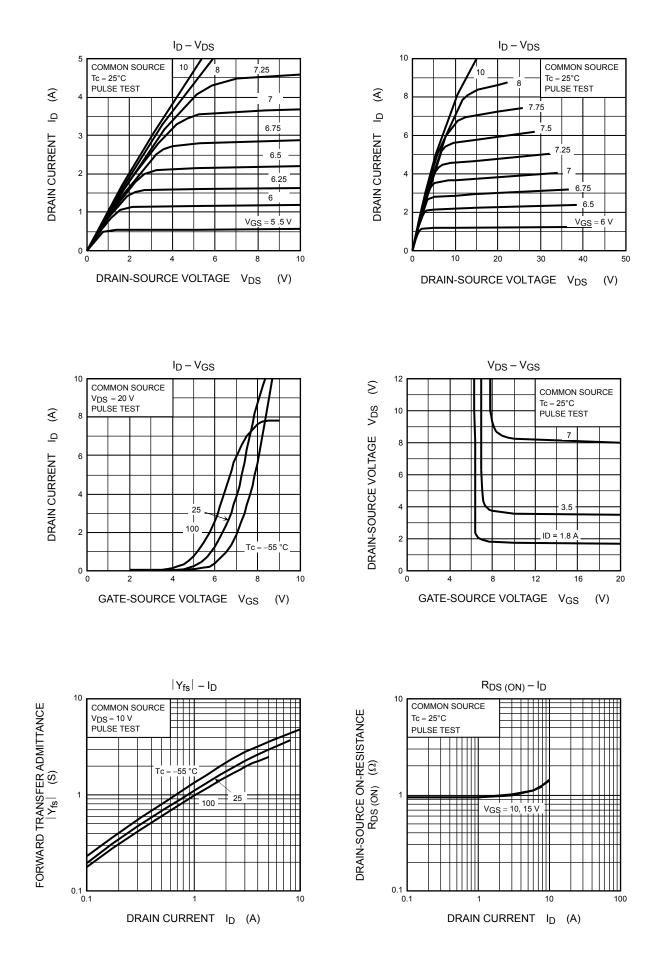
#### Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	—	_	—	7	А
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	—	_	_	28	А
Forward voltage (diode)	V <sub>DSF</sub>	$I_{DR} = 7 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-1.7	V
Reverse recovery time	t <sub>rr</sub>	$I_{DR} = 7 \text{ A}, V_{GS} = 0 \text{ V},$	_	1200	_	ns
Reverse recovery charge	Q <sub>rr</sub>	dl <sub>DR</sub> /dt = 100 A/μs	_	7	_	μC

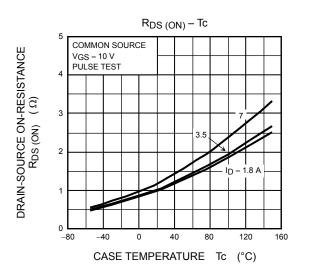
#### Marking

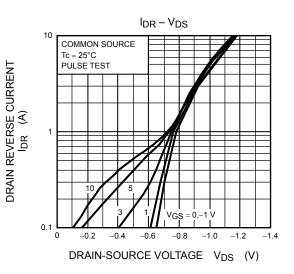


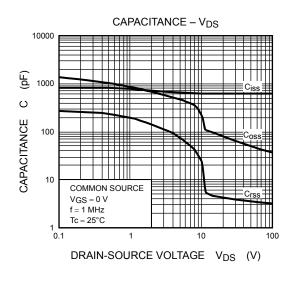
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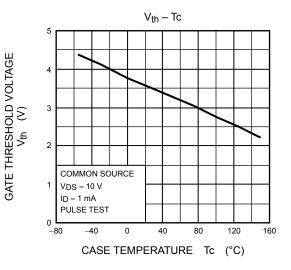


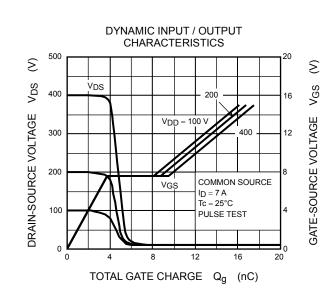
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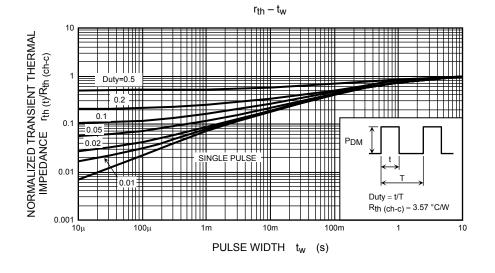


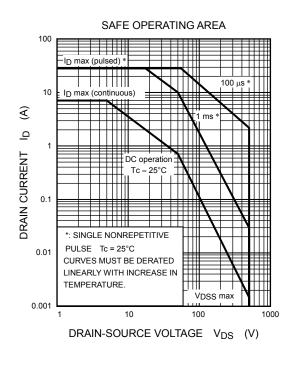


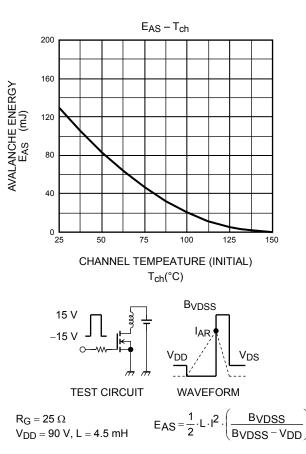


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